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## **Inclosure Material:**

Metal

**Overall Length:** 

0.210 inches

# Terminal Length:

0.500 inches

## **Overall Height:**

0.165 inches

#### **Overall Width:**

0.205 inches

#### Internal Configuration:

#### Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-92

#### **Mounting Method:**

Wountin

# Terminal

Terminal Circle Diameter:

0.105 inches

## **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

25.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 25.0 breakdown voltage, gate-to-source,

with all other terminals short-circuited to source and 10.0 drain to source voltage

#### **Current Rating Per Characteristic:**

10.00 milliamperes gate current

## Power Rating Per Characteristic:

625.0 milliwatts total power dissipation

#### Maximum Operating Tempurature Per Measurement Point:

135.0 degrees celsius junction

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

Fiig:

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